DISCRETE SEMICONDUCTORS

DATA SHEET

PDTC143Z series NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Product data sheet Supersedes data of 2004 Apr 06 2004 Aug 16



NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V_{CEO}	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	4.7	_	kΩ
R2	bias resistor	47	_	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

TYPE NUMBER	PAC	KAGE	MARKING CODE	PNP COMPLEMENT
ITPE NUMBER	PHILIPS	PHILIPS EIAJ		PNP COMPLEMENT
PDTC143ZE	SOT416	SC-75	38	PDTA143ZE
PDTC143ZEF	SOT490	SC-89	53	PDTA143ZEF
PDTC143ZK	SOT346	SC-59	18	PDTA143ZK
PDTC143ZM	SOT883	SC-101	E3	PDTA143ZM
PDTC143ZS	SOT54 (TO-92)	SC-43	TC143Z	PDTA143ZS
PDTC143ZT	SOT23	_	*18 ⁽¹⁾	PDTA143ZT
PDTC143ZU	SOT323	SC-70	*54 ⁽¹⁾	PDTA143ZU

Note

^{1. * =} p: Made in Hong Kong.

^{* =} t: Made in Malaysia.

^{* =} W: Made in China.

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PDTC143Z series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL	PINNING		
ITPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION	
PDTC143ZS		1	base	
		2	collector	
	R1 R2 3 MAM364	3	emitter	
PDTC143ZE PDTC143ZEF PDTC143ZK PDTC143ZT PDTC143ZU	Top view Top view Top view Top view	1 2 3	base emitter collector	
PDTC143ZM	2 R1 R2 2 bottom view MHC506	1 2 3	base emitter collector	

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

ORDERING INFORMATION

TYPE NUMBER		PACKAGE				
ITPE NUMBER	NAME	DESCRIPTION				
PDTC143ZE	_	plastic surface mounted package; 3 leads	SOT416			
PDTC143ZEF	-	plastic surface mounted package; 3 leads	SOT490			
PDTC143ZK	_	 plastic surface mounted package; 3 leads 				
PDTC143ZM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm	SOT883			
PDTC143ZS	_	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
PDTC143ZT	_	plastic surface mounted package; 3 leads	SOT23			
PDTC143ZU	_	plastic surface mounted package; 3 leads	SOT323			

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base	_	50	V
V_{EBO}	emitter-base voltage	open collector	_	10	V
VI	input voltage				
	positive		_	+30	V
	negative		_	-5	V
Io	output current (DC)		_	100	mA
I _{CM}	peak collector current		_	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	_	150	mW
	SOT490	notes 1 and 2	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

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PDTC143Z series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μm copper strip line.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

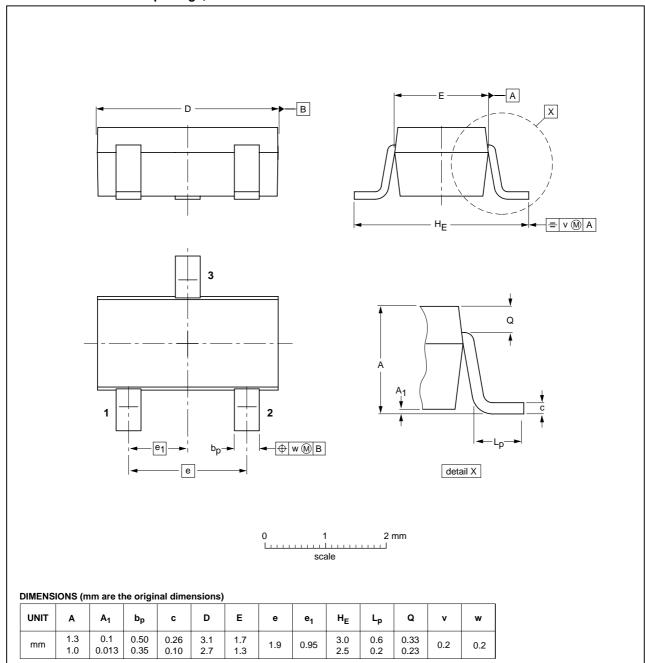
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	_	_	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	_	_	1	μΑ
		$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}; T_{j} = 150 ^{\circ}\text{C}$	_	_	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	_	_	170	μΑ
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA}$	100	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 5 \text{ mA}; I_B = 0.25 \text{ mA}$	_	_	100	mV
$V_{i(off)}$	input-off voltage	$I_C = 100 \mu A; V_{CE} = 5 V$	_	0.6	0.5	V
$V_{i(on)}$	input-on voltage	$I_C = 5 \text{ mA}; V_{CE} = 0.3 \text{ V}$	1.3	0.9	_	V
R1	input resistor		3.3	4.7	6.1	kΩ
<u>R2</u> R1	resistor ratio		8	10	12	
C _c	collector capacitance	$I_E = I_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	_	_	2.5	pF

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PDTC143Z series

PACKAGE OUTLINES

Plastic surface-mounted package; 3 leads SOT346



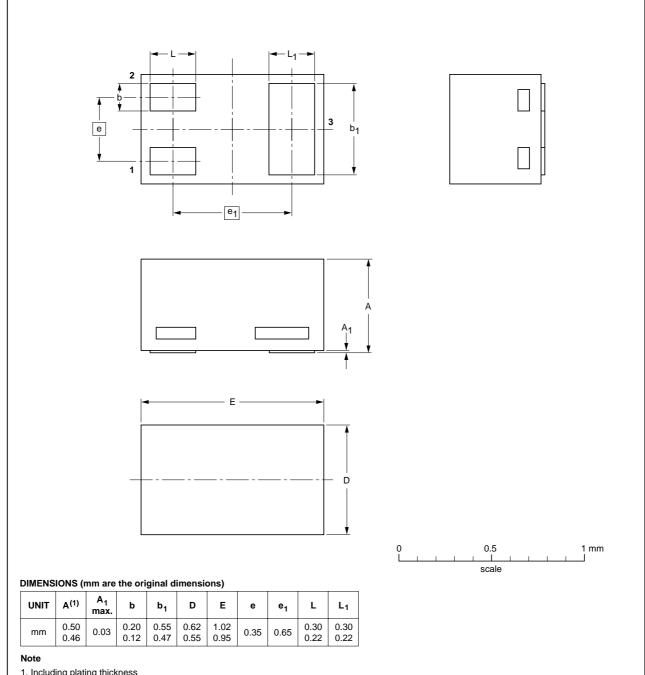
OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A			-04-11-11 06-03-16	

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883



1. Including plating thickness

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT883			SC-101		03-02-05 03-04-03	

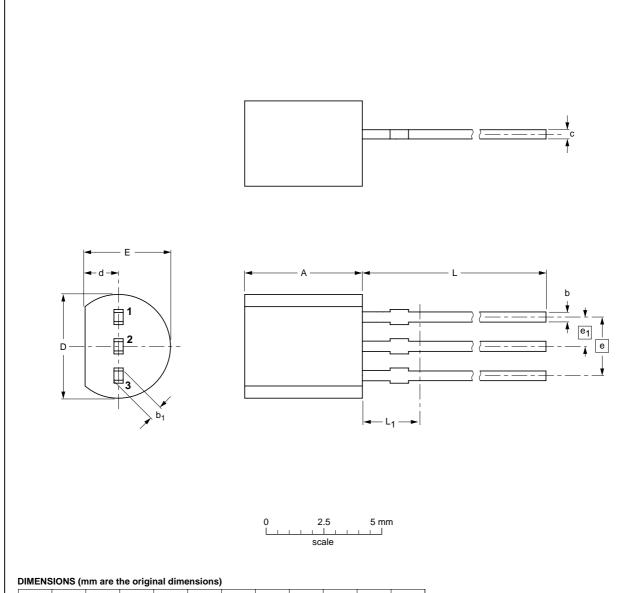
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NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	Α	b	b ₁	С	D	d	E	е	e ₁	L	L ₁ ⁽¹⁾ max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

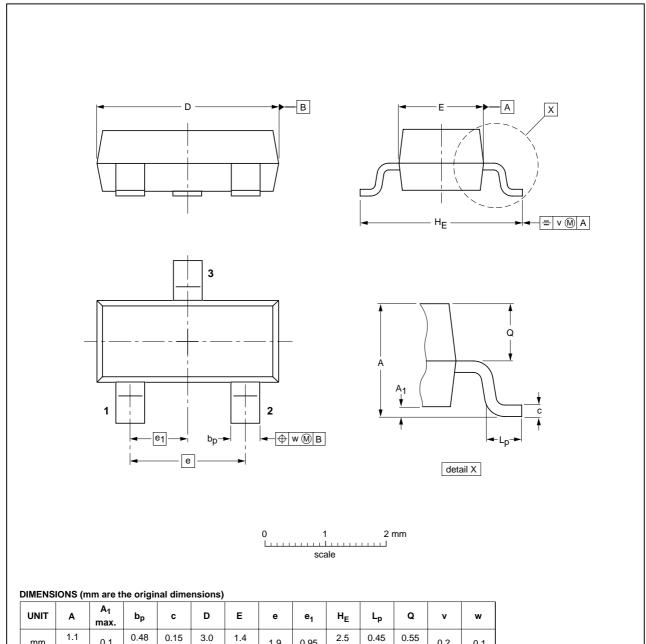
OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT54		TO-92	SC-43A		-04-06-28- 04-11-16	

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT23		TO-236AB				-04-11-04- 06-03-16	

0.2

0.1

1.9

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0.38

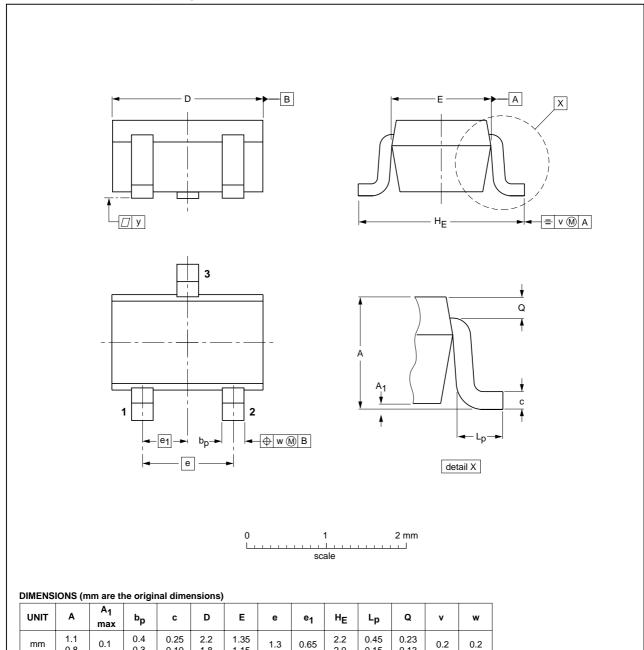
0.9

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT323



OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT323			SC-70		04-11-04 06-03-16

10

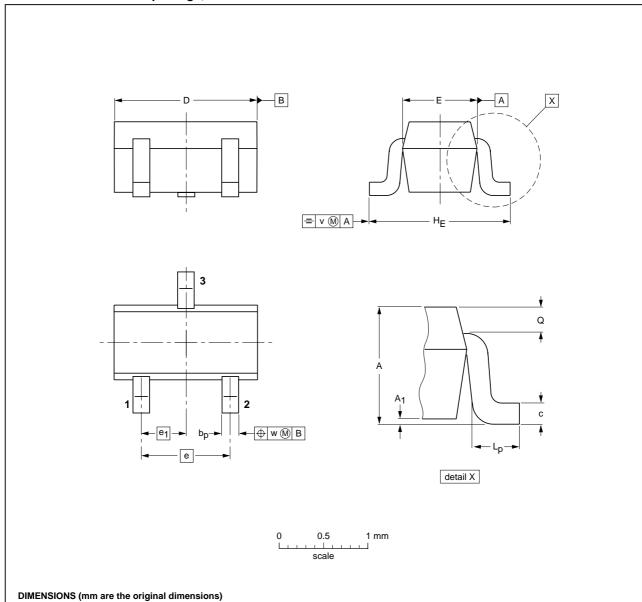
0.3

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT416



UNIT	Α	A ₁ max	bp	С	D	E	е	e ₁	HE	Lp	ø	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT416			SC-75		04-11-04 06-03-16

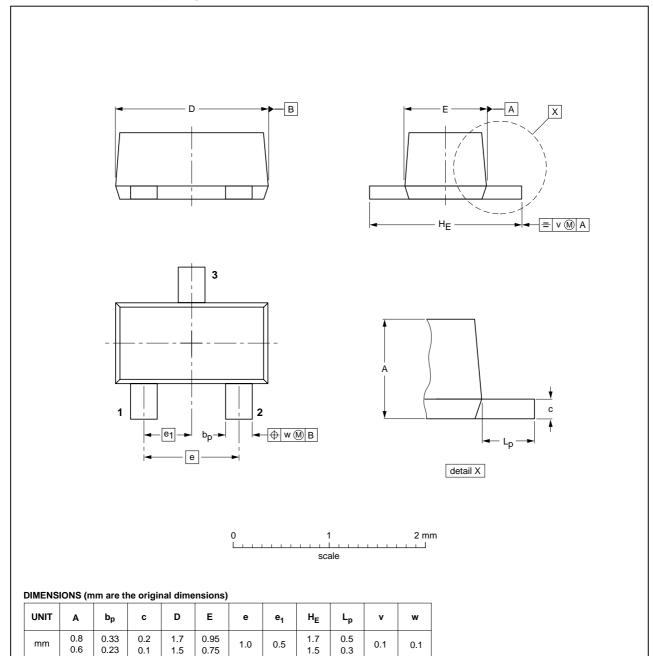
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NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

Plastic surface-mounted package; 3 leads

SOT490



VERSION IEC JEDEC JEITA PROJECTION 95-07	OUTLINE		REFER	ENCES	 EUROPEAN	ISSUE DATE
	VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
30-09 06-03	SOT490			SC-89		05-07-28 06-03-16

NPN resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

PDTC143Z series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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Contact information

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